

# SILICON TRANSISTORS 2SD1615, 2SD1615A

## NPN SILICON EPITAXIAL TRANSISTORS POWER MINI MOLD

### DESCRIPTION

2SD1615, 1615A are designed for audio frequency power amplifier and switching application, especially in Hybrid Integrated Circuits.

### FEATURES

- World Standard Miniature Package
- Low  $V_{CE(sat)}$   $V_{CE(sat)} = 0.15$  V
- Complement to 2SB1115, 2SD1115A

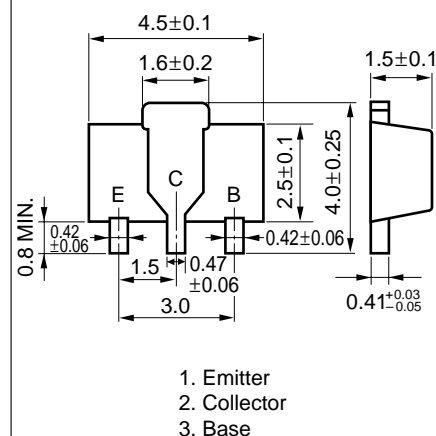
### ABSOLUTE MAXIMUM RATINGS

Maximum Voltages and Currents ( $T_A = 25^\circ\text{C}$ )	2SD1615	2SD1615A	
Collector to Base Voltage	$V_{CBO}$ 60	120	V
Collector to Emitter Voltage	$V_{CEO}$ 50	60	V
Emitter to Base Voltage	$V_{EBO}$	6	V
Collector Current (DC)	$I_C$	1	A
Collector Current (Pulse)*	$I_C$	2	A
Maximum Power Dissipation			
Total Power Dissipation			
at $25^\circ\text{C}$ Ambient Temperature**	$P_T$	2.0	W
Maximum Temperatures			
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55 to +150	$^\circ\text{C}$

\*  $PW \leq 10$  ms, Duty Cycle  $\leq 50\%$

\*\* When mounted on ceramic substrate of  $16\text{ cm}^2 \times 0.7\text{ mm}$

### PACKAGE DIMENSIONS in millimeters



### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Collector Cutoff Current	$I_{CBO}$			100	nA	2SD1615	$V_{CB} = 60\text{ V}, I_E = 0$
				100	nA	2SD1615A	$V_{CB} = 120\text{ V}, I_E = 0$
Emitter Cutoff Current	$I_{EBO}$			100	nA	$V_{EB} = 6.0\text{ V}, I_C = 0$	
DC Current Gain	$h_{FE1}^{***}$	135	290	600		2SC1615	$V_{CE} = 2.0\text{ V}, I_C = 100\text{ mA}$
		135		400		2SD1615A	
DC Current Gain	$h_{FE2}^{***}$	81	270			$V_{CE} = 2.0\text{ V}, I_C = 1.0\text{ A}$	
Collector Saturation Voltage	$V_{CE(sat)}^{***}$		0.15	0.3	V	$I_C = 1.0\text{ A}, I_B = 50\text{ mA}$	
Base Saturation Voltage	$V_{BE(sat)}^{***}$		0.9	1.2	V	$I_C = 1.0\text{ A}, I_B = 50\text{ mA}$	
Base to Emitter Voltage	$V_{BE}^{***}$	600		700	mV	$V_{CE} = 2.0\text{ V}, I_C = 50\text{ mA}$	
Gain Bandwidth Product	$f_T$	80	160		MHz	$V_{CE} = 2.0\text{ V}, I_E = -100\text{ mA}$	
Output Capacitance	$C_{ob}$		19		pF	$V_{CB} = 10\text{ V}, I_E = 0, f = 1.0\text{ MHz}$	

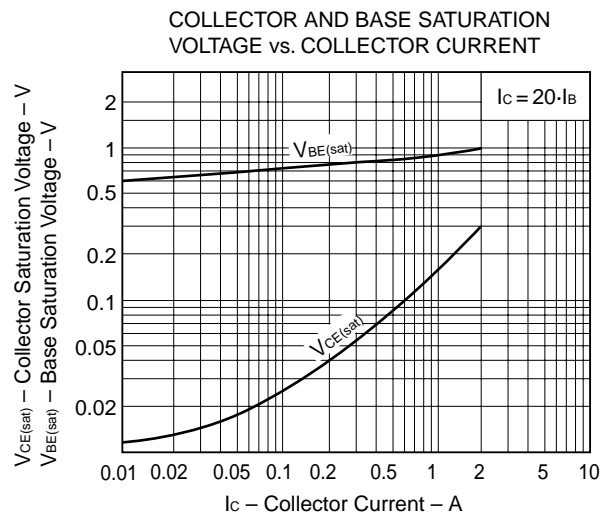
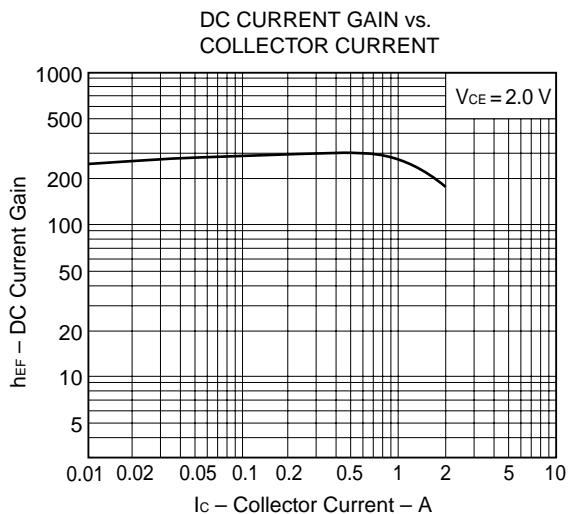
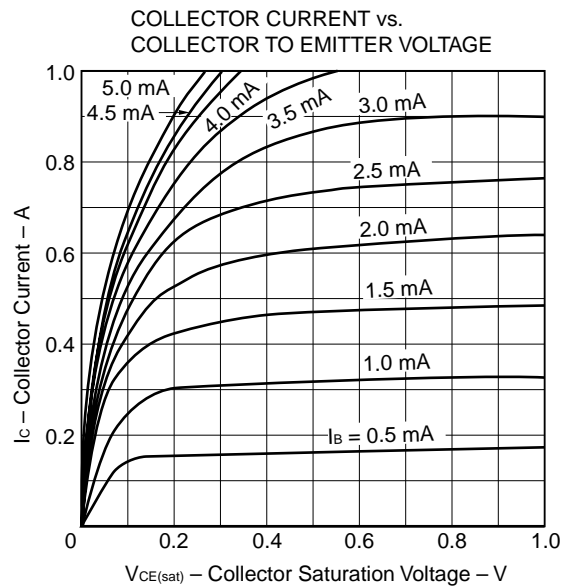
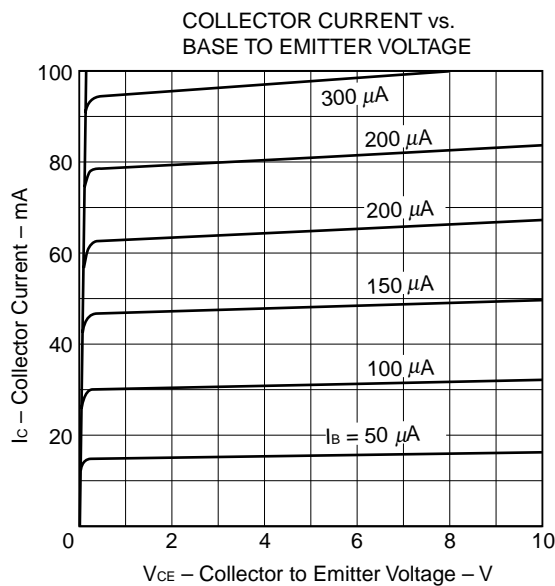
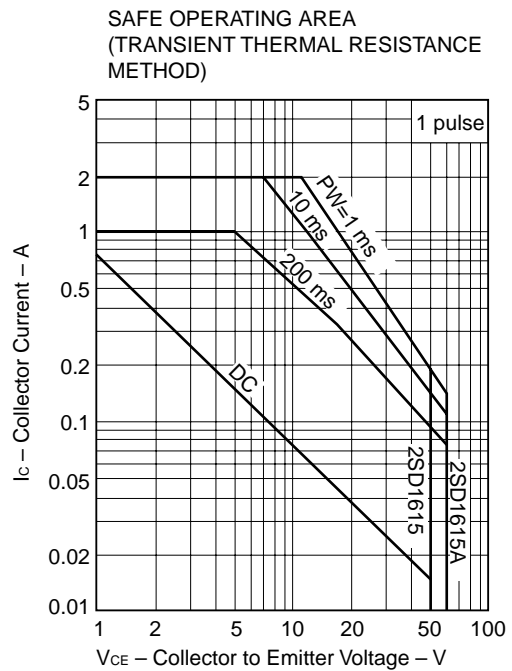
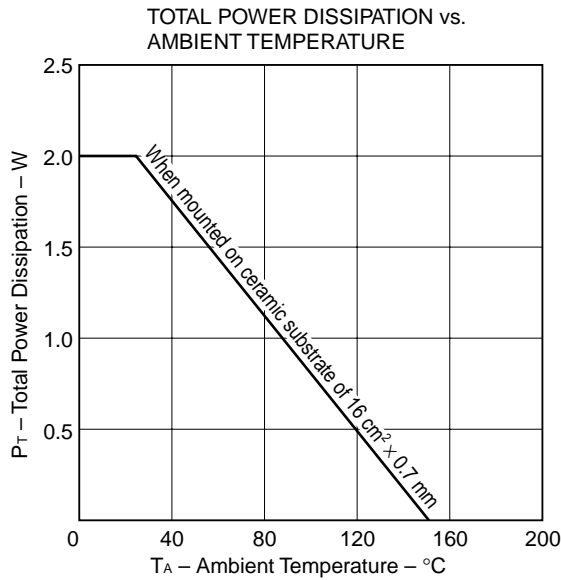
\*\*\* Pulsed:  $PW \leq 350\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2\%$

### $h_{FE}$ Classification

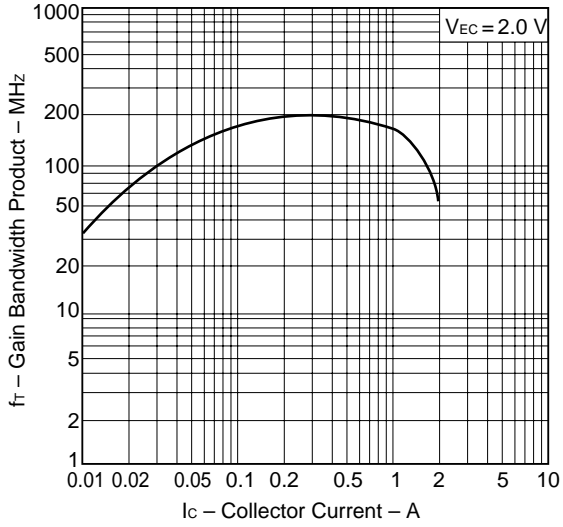
MARKING	2SD1615	GM	GL	GK
	2SD1615A	GQ	GP	
$h_{FE}$	135 to 270	200 to 400	300 to 600	

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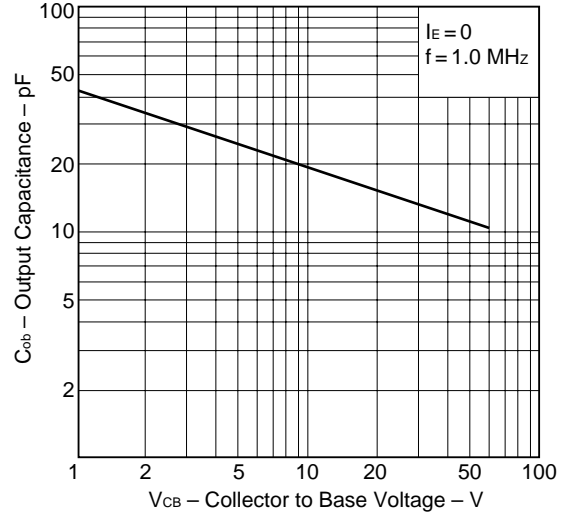
TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)



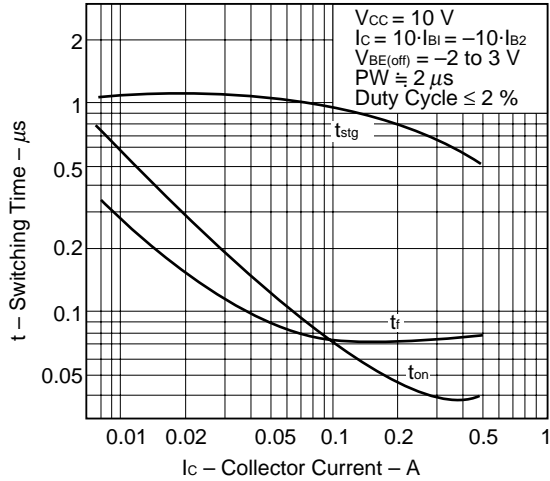
GAIN BANDWIDTH PRODUCT vs. EMITTER CURRENT



OUTPUT CAPCITANCE vs. COLLECTOR TO BASE VOLTAGE



SWITCHING TIME vs. COLLECTOR CURRENT



[MEMO]

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